NSN 5962-01-159-0966

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View Online at https://aerobasegroup.com/nsn/5962-01-159-0966
Body Length:
Between 1.380 inches and 1.430 inches
Body Width:
Between 0.580 inches and 0.610 inches
Body Height:
Between 0.080 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5820-01-148-3976 radio terminal set
Features Provided:
Monolithic and programmable and hermetically sealed and w/open collector
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
17 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Pal
Test Data Document:
49956-954387 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a

Yes - demil/mli

Unit Of Measure:

Demilitarization:

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